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Datasheet

Optocoupler-less

Isolated Flyback Converter

BD7F200HFN-LB BD7F200EFJ-LB BD7F200UEFJ-LB

General Description

This product guarantees long time supply availability in the industrial instrumentation market.

BD7F200 is an optocoupler-less Isolated Flyback Converter. An optocoupler or the tertiary winding feedback circuit which was needed to obtain a stable output voltage isolated by a transformer in the conventional application becomes unnecessary, thus, the number of parts is reduced drastically, producing a small-sized and high-reliability application isolated type power supply.

Furthermore, a highly by the use of the Original Adapted-Type ON-Time Control Technology, it makes the external phase compensation parts become unnecessary, therefore a highly efficient isolated type power supply application can easily be produced.

Features

- Guaranteed long time supply availability for Industrial Applications.
- No need for an optocoupler or a transformer tertiary winding.
  The output voltage can be set by two external resistors and the transformer turns ratio.
- Uses Original Adapted Type ON-Time Control Technology.
  High-speed load response is realized and external phase compensation parts are unnecessary.
- Fixed switching frequency and low output ripple
- Highly efficient light load mode available (PFM operation)
- Shutdown / Enable Control
- Built-in N-Channel MOSFET
- Soft start function
- Output load compensation function
- Protection functions:
  VIN Under Voltage Lock-Out (VIN UVLO)
  Over Current Protection (OCP)
  Thermal Shutdown Protection (TSD)

Application

- Industrial equipment Isolated Power Supply

Key Specifications

- Supply Voltage of Operation: 8V to 40V
- SW Terminal Operating Voltage: 50V (Max)
- Over Current Limit: 2.75A (Typ)
- Switching Frequency: 400kHz (Typ)
- Reference Voltage Accuracy: ±1.5% (Typ)
- Quiescent Current: 0μA (Typ)
- Operating Current: 2mA (Typ)
- Junction Temperature of Operation: -40°C to +125°C

Packages	W(Typ)	D(Typ)	H(Max)
HSON8	2.90mm x 3.00mm x 0.60mm		
HTSOP-J8	4.90mm x 6.00mm x 1.00mm		



HSON8

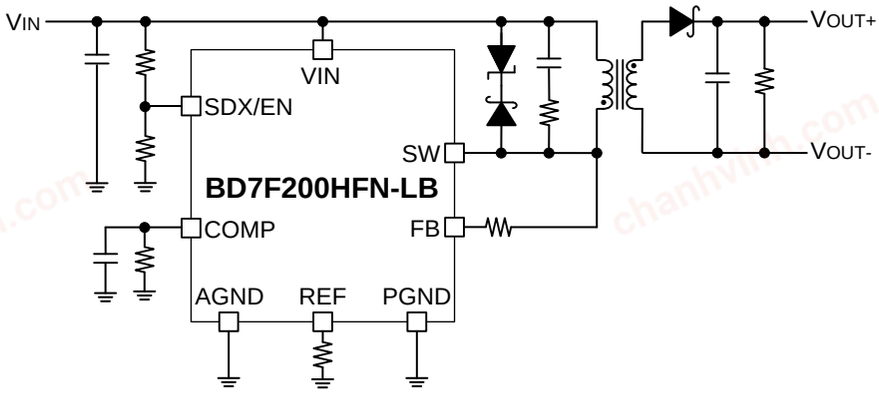


HTSOP-J8

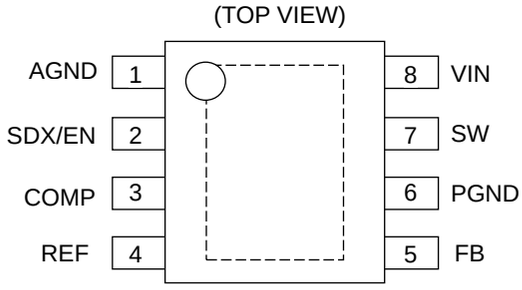
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Typical Application Circuit



Pin Configuration



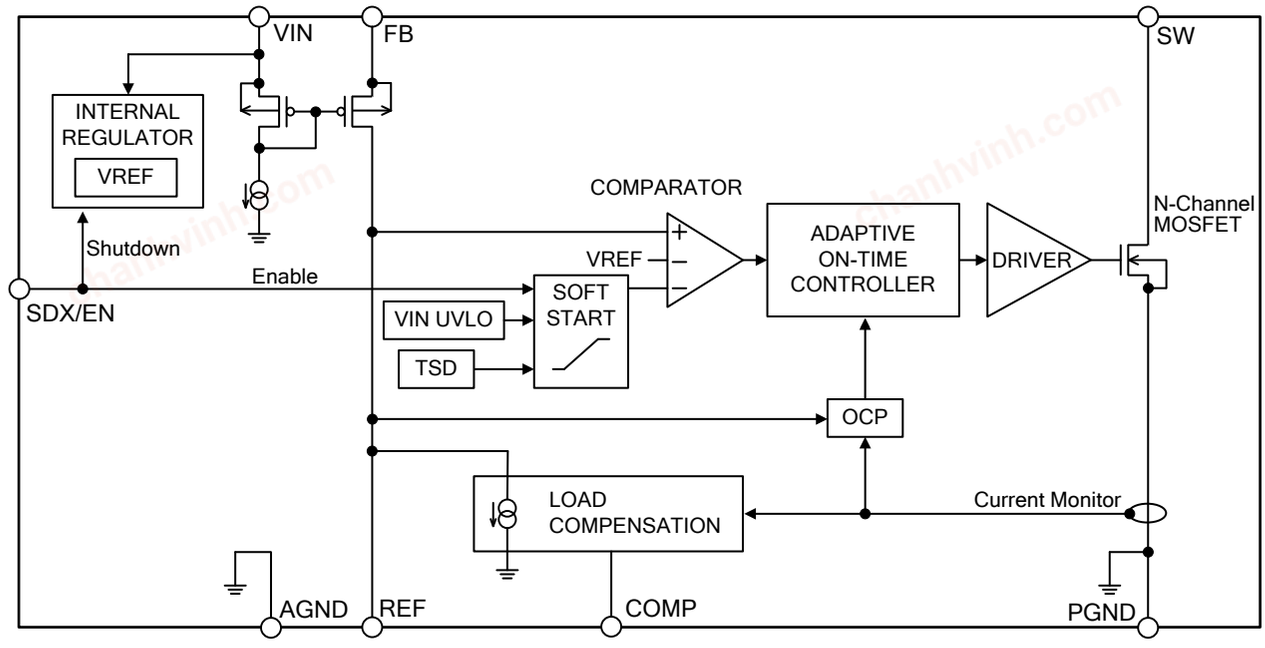
Pin Descriptions

Pin No.		Pin Name	Function
HSON8	HTSOP-J8		
1	1	AGND	Analog system GND
2	2	SDX/EN	Shutdown/Enable control
3	3	COMP	Load Current Compensation of the output voltage set up
4	4	REF	Output voltage setup
5	5	FB	Output voltage setup
6	6	PGND	Power system GND
7	7	SW	Switching Output
8	8	VIN	Power supply

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Block Diagram



Description of Blocks

1. INTERNAL REGULATOR
   This is the regulator block for internal circuits.
   Also includes a reference voltage generating block (VREF).
   This block is in the shutdown state when the SDX/EN terminal is below 0.9V (Typ).

2. VIN UVLO
   This is the input low-voltage-protection block.
   If the power supply input voltage, V_{IN}, falls to below 6.2V (Typ), it will be detected and this block will be in the protection state and the SW terminal becomes Hi-Z.
   When the power supply input voltage (V_{IN}) rises to 6.9V (Typ), it automatically recovers thorough the soft start.
   (Hysteresis voltage: 0.7V (Typ).)

3. SOFT START
   When the SDX/EN terminal is in the enable state with more than 2.0V (Typ), this block prevents inrush current and overshoot in the rising of the output voltage by making the reference voltage of the COMPARATOR block rise slowly from 0V to VREF voltage.
   The default soft start time, t_{SS}, is designed to be 6ms (Typ) internally.
   The min off time is 750ns (Typ) when the output voltage is below 50% of the set voltage.

4. COMPARATOR
   This is the block which compares the reference voltage VREF with the REF terminal voltage which is the feedback voltage of the SW terminal voltage.
   Since the feedback loop is structured by a comparator is established, it has excellent response to load fluctuation.

5. ADAPTIVE ON-TIME CONTROLLER
   This is the block corresponding to the original adapted type ON-Time control technology.
   Switching frequency is fixed at 400kHz (Typ) under PWM Control when the load is stable.
   Under On-Time Control, when the load varies, fast load response is enabled by changing the switching frequency.
   During light load, the highly efficient PFM will operate and the self-power dissipation is suppressed by decreasing the switching frequency.

6. DRIVER
   This is the block which drives the built-in N-Channel MOSFET.

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Description of Blocks - continued

7. LOAD COMPENSATION
   This is the block which compensates the output voltage regulation by VF characteristic fluctuation of the secondary side output diode according to the load current.
   The current which flows into the built-in N-Channel MOSFET is monitored, and the current according to the compensation quantity and the time constant which are determined by the external resistor and the capacitor of the COMP terminal is drawn from the REF terminal. The output voltage rises and is rectified when feedback current which flows into the external resistor of the REF terminal decreases and the REF terminal voltage falls.

8. TSD
   This is the temperature protection block.
   If the chip's junction temperature, Tj, inside the IC is above 175°C (Typ), it will be detected and this block will be in the protection state and the SW terminal becomes Hi-Z.
   If Tj falls to below 150°C (Typ), it will return automatically through soft start.

9. OCP
   This is the over-current protection block.
   If the peak current during the ON-Time of the built-in N-Channel MOSFET reaches 2.75A (Typ), it will be detected and the N-Channel MOSFET is turned OFF.
   If output voltage goes to 50% or less of the setting voltage, the peak detection current of OCP will be controlled by 1.6A (Typ).The min off time is 1.5μs (Typ) when the OCP is operated under the condition where the output voltage is 50% of the set voltage.

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating		Unit
		BD7F200HFN-LB	BD7F200EFJ-LB BD7F200UEFJ-LB	
VIN Input Power Voltage *(Note 1)*	V_{IN}	45		V
SW Terminal Voltage	V_{SW}	60		V
SDX/EN Terminal Voltage	$V_{SDX/EN}$	V_{IN}		V
FB Terminal Voltage	V_{FB}	V_{IN}-0.3V to lower value of V_{IN}+0.3V or 45V		V
REF Terminal Voltage	V_{REF}	7		V
COMP Terminal Voltage	V_{COMP}	7		V
Power Dissipation	Pd	1.75 *(Note 2)*	3.75 *(Note 3)*	W
Storage Temperature Range	Tstg	-55 to +150		°C
Maximum Junction Temperature	Tjmax	150		°C

(Note 1) Not to exceed Power Dissipation (Pd).
(Note 2) Reduced by 14.0mW/°C for temperatures above 25°C (when mounted on a one-layer glass-epoxy board with 70mm × 70mm × 1.6mm dimension, 65% copper foil density)
(Note 3) Reduced by 30.0mW/°C for temperatures above 25°C (when mounted on four-layer glass-epoxy board with 70mm × 70mm × 1.6mm dimension.)
Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions

Parameter	Symbol	Limit			Unit
		Min	Typ	Max	
VIN Input Power Voltage	V_{IN}	8	24	40	V
SW Terminal Voltage	V_{SW}	-	-	50	V
Junction Temperature *(Note4)*	Tj	-40	-	+125	°C

(Note 4) Life time is derated at junction temperature greater than 125°C.

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Electrical Characteristics (Unless otherwise specified Ta = 25°C, V_{IN} = 24V, and $V_{SDX/EN}$ = 2.5V.)

Parameter	Symbol	Limit			Unit	Conditions
		Min	Typ	Max		
Power Supply						
Quiescent Current	I_{ST}	-	0	10	μA	$V_{SDX/EN}$ = 0V
Operating Current	I_{CC}	-	2	4	mA	$V_{SDX/EN}$ = 2.5V V_{REF} = 2V (at PFM operation)
UVLO Detection Voltage	V_{UVLO}	5.7	6.2	6.7	V	V_{IN} falling
UVLO Hysteresis Voltage	V_{UVLO_HYS}	0.6	0.7	0.8	V	
SDX/EN Control						
Shutdown Voltage	V_{SDX}	0.3	0.9	1.5	V	
Enable Voltage	V_{EN}	1.9	2.0	2.1	V	$V_{SDX/EN}$ rising
Enable Hysteresis Voltage	V_{EN_HYS}	0.15	0.2	0.25	V	
SDX/EN Input Current	$I_{SDX/EN}$	-	0	1	μA	$V_{SDX/EN}$=2V
Reference Voltage						
Reference Voltage	V_{REF}	0.768	0.78	0.792	V	
Switch Characteristics						
ON-Resistance	R_{ON}	-	0.5	-	Ω	Between SW - PGND terminals
Over Current Limit	I_{LIMIT}	2.2	2.75	3.3	A	
Switching Frequency	f_{SW}	-	400	-	kHz	At PWM operation (Duty=40%)
Minimum ON Time	t_{ON_MIN}	-	350	-	ns	
Minimum OFF Time	t_{OFF_MIN}	-	300	-	ns	
Maximum OFF Time	t_{OFF_MAX}	-	20	-	μs	
Soft Start Time	t_{SS}	-	6	-	ms	0V to (V_{REF} × 90%)

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Typical Performance Curves

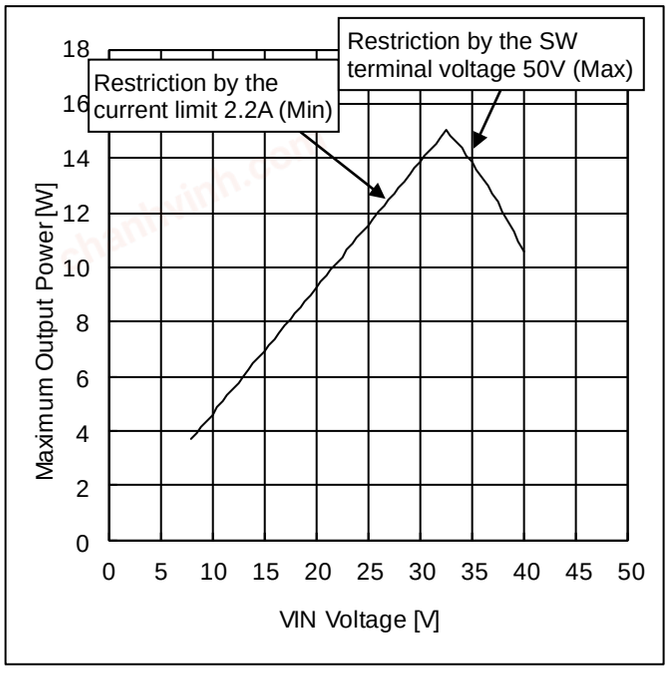


Figure 1. Maximum Output Power vs VIN Voltage

Maximum output power is restricted in general by a current limit and the maximum operating voltage of SW terminal. Furthermore, it also changes with the characteristics of external parts (Transformer, Schottky barrier diode, Snubber circuit, etc.).

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Typical Performance Curves

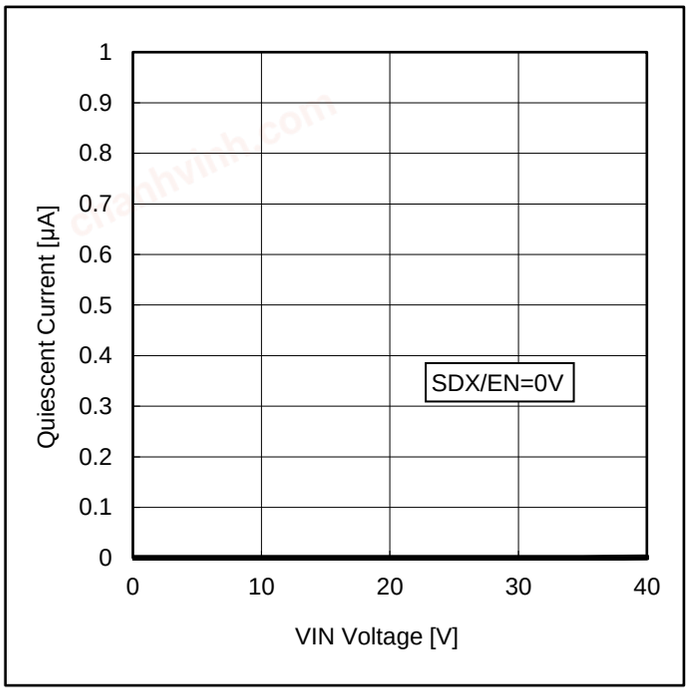


Figure 2. Quiescent Current vs VIN Voltage

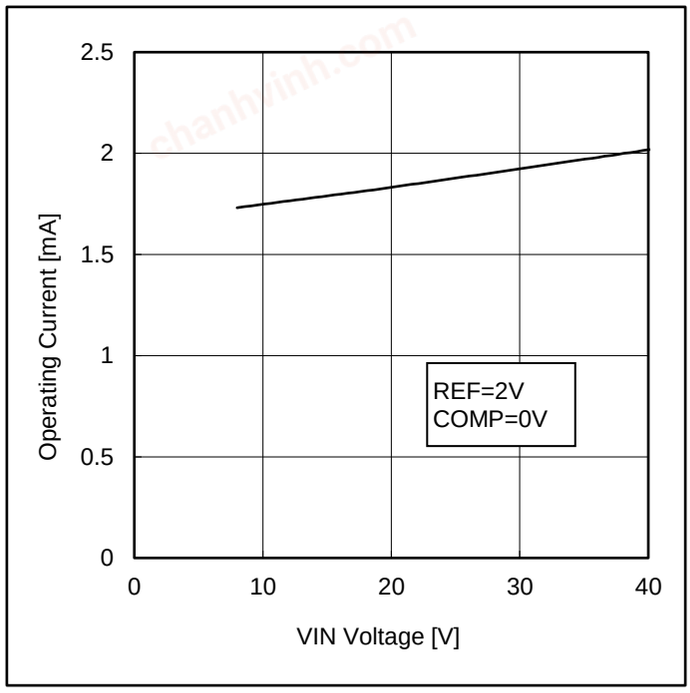


Figure 3. Operating Current vs VIN Voltage

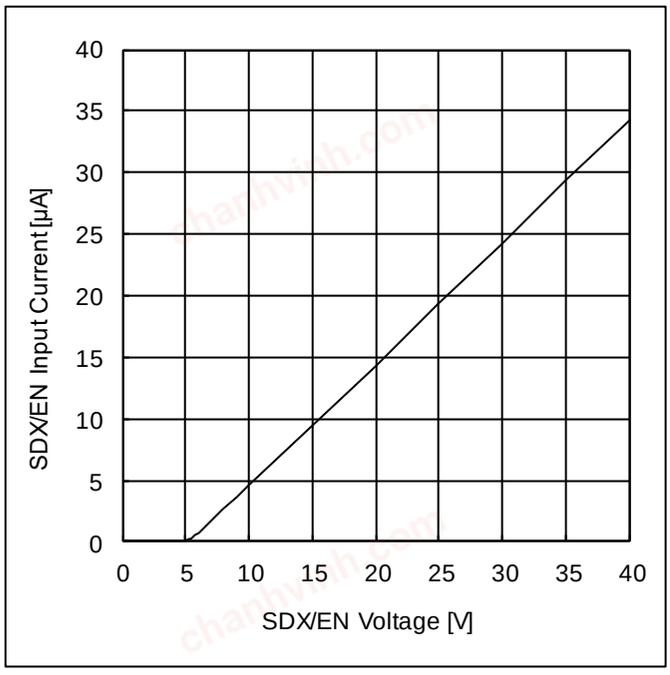


Figure 4. SDX/EN Input Current vs SDX/EN Voltage

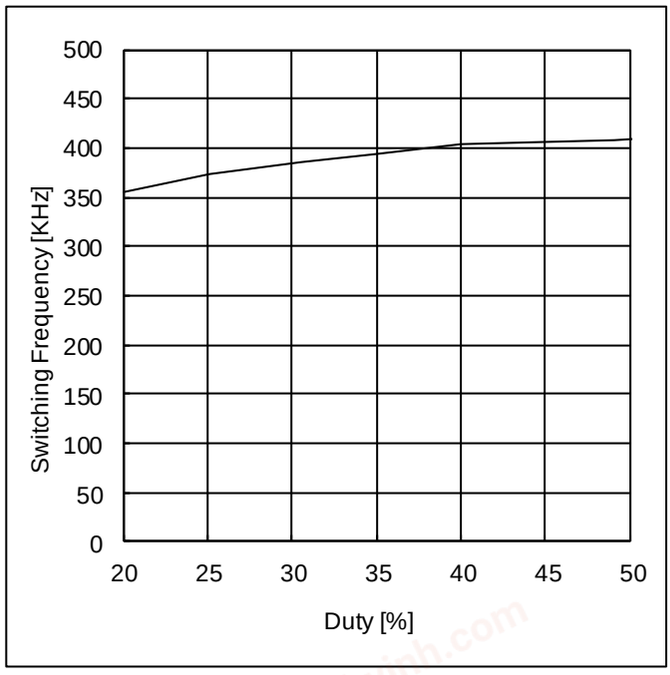


Figure 5. Switching Frequency vs Duty

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Typical Performance Curves

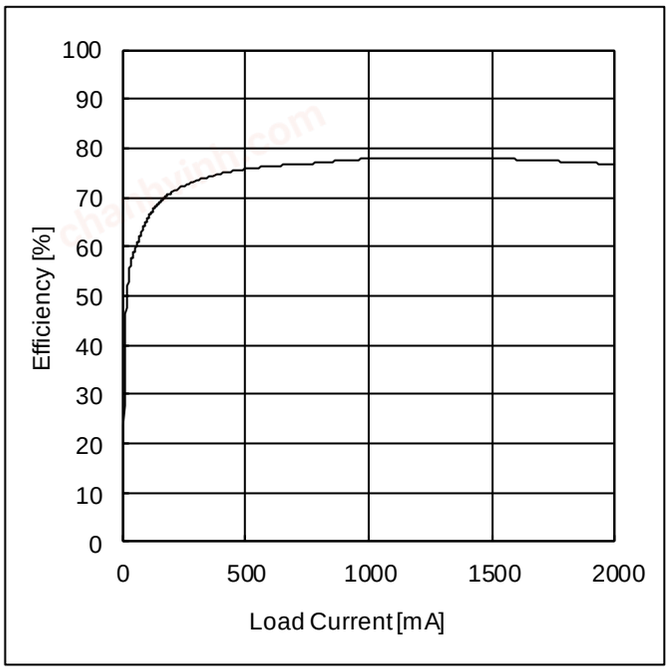


Figure 6. Efficiency vs Load Current
(24V Input, 5V Output)

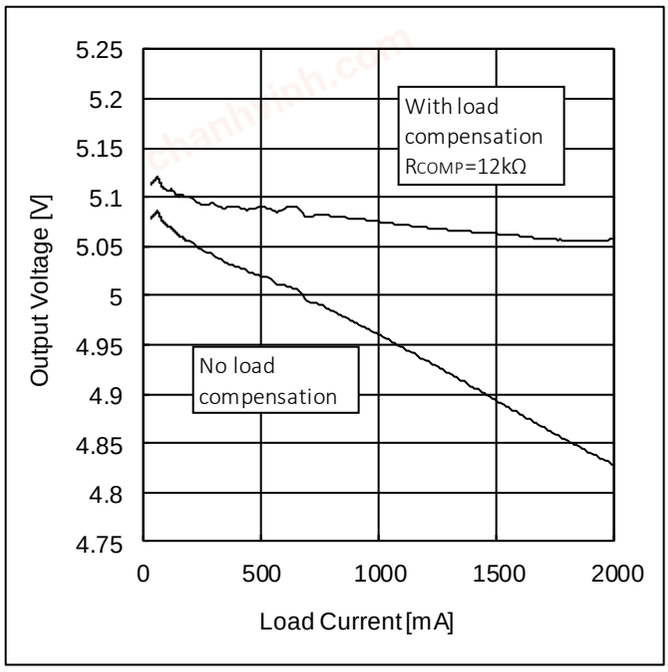


Figure 7. Output Voltage vs Load Current
(24V Input, 5V Output)

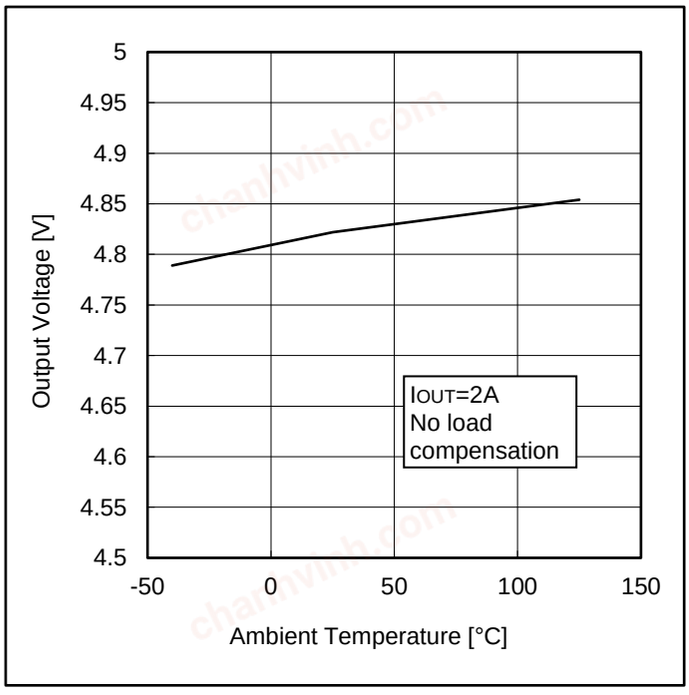
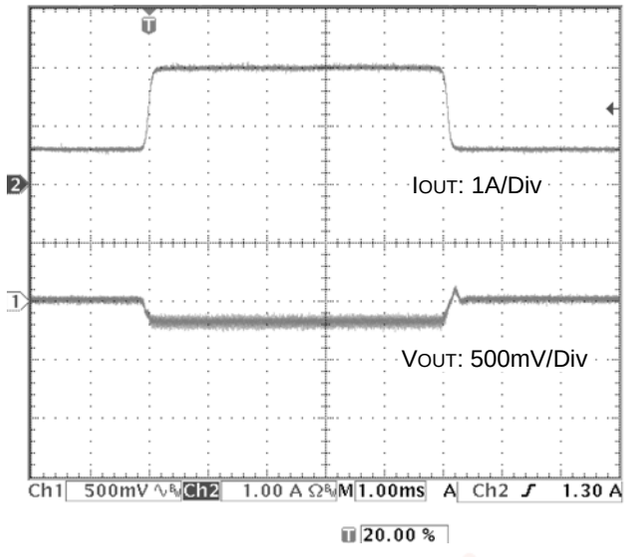


Figure 8. Output Voltage vs Ambient Temperature
(24V Input, 5V Output)



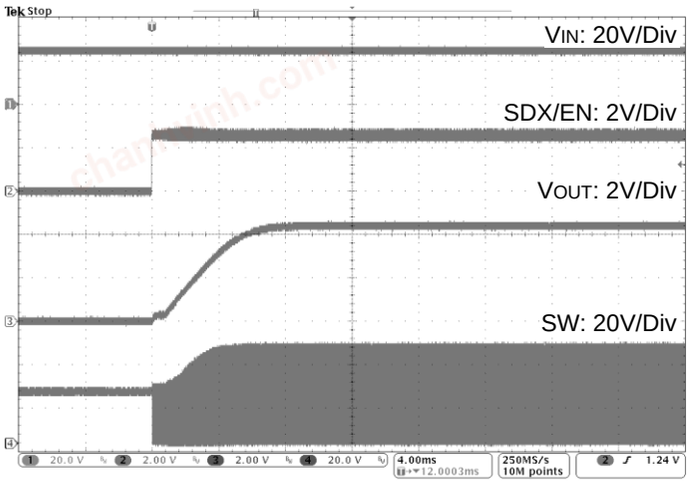
Time: 1ms/Div

Figure 9. Load Transient Response
(24V Input, 5V Output, with Load Compensation,
and IOUT = 600mA <-> 2A)

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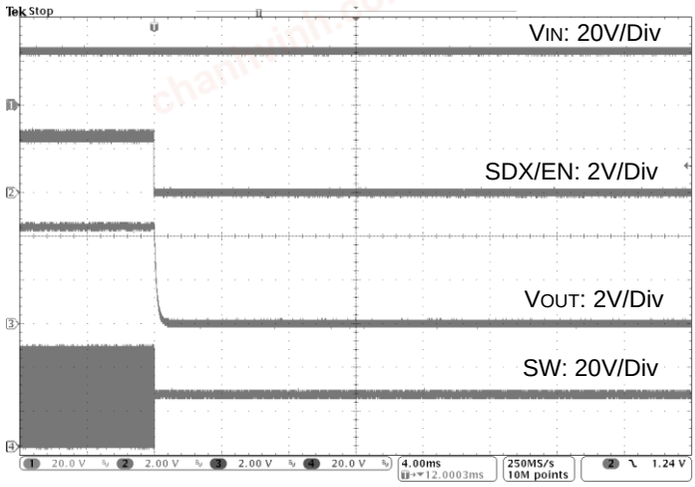
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Typical Performance Curves



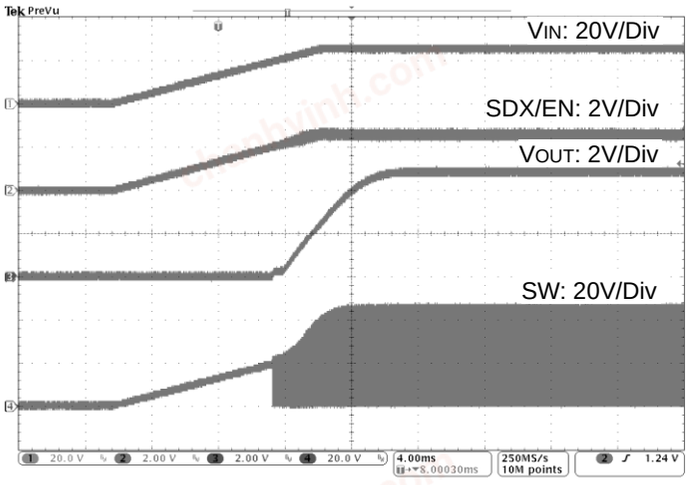
Time: 4ms/Div

Figure 10. Start Up Wave Forms(SDX/EN control)
(24V Input, 5V Output, SDX/EN=0V->2.5V)



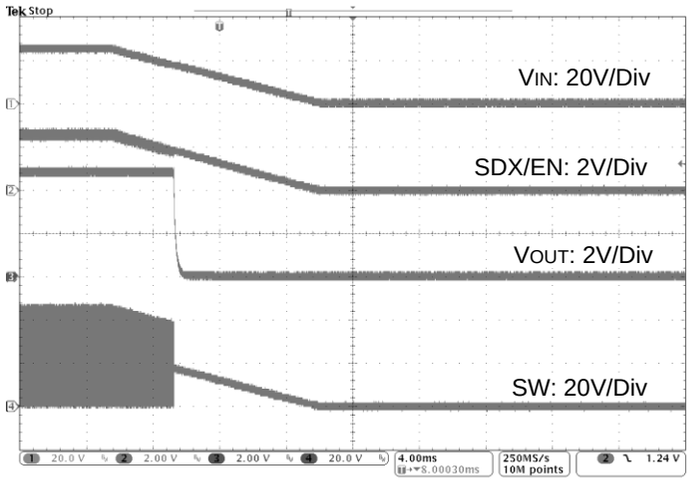
Time: 4ms/Div

Figure 11. Shutdown Waveforms (SDX/EN control)
(24V Input, 5V Output, SDX/EN=2.5V->0V)



Time: 4ms/Div

Figure 12. Start Up Wave Forms(VIN control)
(24V Input, 0V Output, VIN=0V->24V, R_1=1MΩ, R_2=120kΩ)



Time: 4ms/Div

Figure 13. Shutdown Waveforms(VIN control)
(24V Input, 5V Output, VIN=24V->0V, R_1=1MΩ, R_2=120kΩ)

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Application Examples

Exercise caution with the actual system since the characteristic changes with the board layout and the types of external parts mounted, and etc.

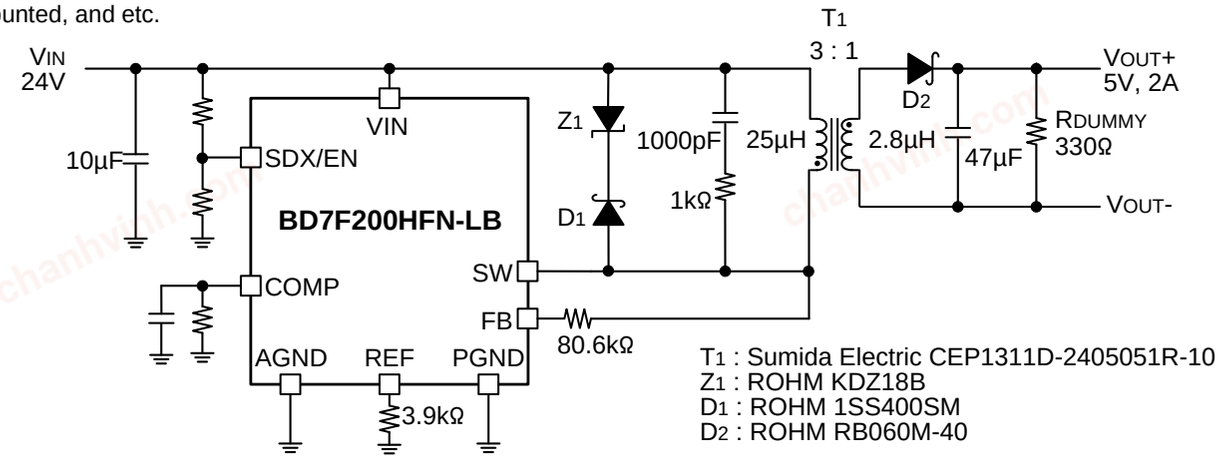


Figure 14. 24V Input, 5V Output

Table1. Recommended Transformers

Part Number	Size (W × L × H) [mm]	LP [µH]	NP : NS	Vendor	Target Applications		
					VIN [V]	VOUT [V]	IOUT [A]
CEP1311D-2405051R-10	13.5 × 20.0 × 12.5	25	3 : 1	Sumida Electric	24	5	2

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Application Information

1. Outline Operation

This product is an isolated type flyback converter without an optocoupler. An optocoupler or a transformer's tertiary winding feedback circuit which was needed to obtain a stable output voltage isolated by a transformer in the conventional application becomes unnecessary, thus, the number of parts is reduced drastically, producing a small-sized and high-reliability application isolated type power supply.
Furthermore, a highly efficient isolated type power supply application can easily be produced the use of the Original Adapted-Type ON-Time Control Technology which eliminates the need for external phase compensation parts.
The off time is determined by comparing the reference voltage inside the IC with the information which was obtained by the feedback of the secondary output voltage through primary flyback voltage.

Adapted-type ON time control,
(1) Switching frequency is fixed at 400kHz (Typ) for PWM operation when the load stabilizes.
(2) During load current fluctuation, the ON-Time Control will operate and the switching frequency will change, thus a high-speed load response is obtained.
(3) During light load, high efficiency is obtained because the switching frequency decreases.

2. Timing Chart

(1)Start-up/Shut-down
Output voltage gradually turns ON through the soft start function when SDX/EN terminal rises to above 2.0V(Typ) (Enable state) .When SDX/EN terminal falls below 1.8V (Typ), output voltage turns OFF (Disable state).

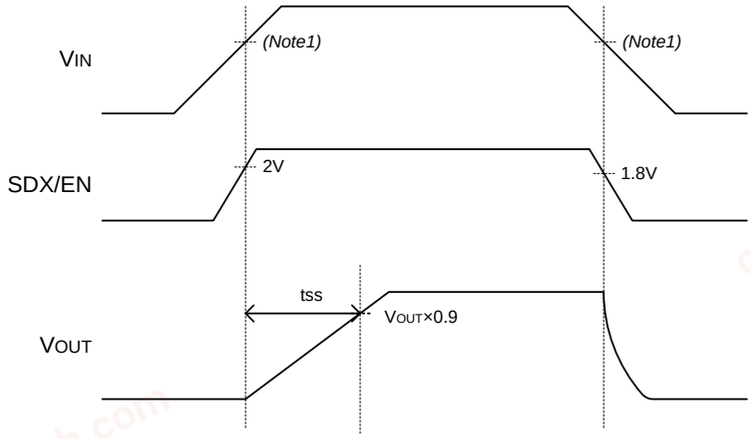


Figure 15. Start-up/Shut-down Timing Chart

(Note 1) In the control system of this IC, it has to be operated where duty is below 50%. When turning ON/OFF the IC, control the SDX/EN terminal as enable/disable under the condition where VIN fulfills below equation.

$$V_{IN} > \frac{N_P}{N_S} \times \left(V_{OUT} + V_F\right) \quad [\mathrm{V}]$$

where:
V_{IN} is the VIN input power voltage
N_P is the number of turns in the transformer primary side
N_S is the number of turns in the transformer secondary side
V_{OUT} is the output voltage
V_F is the forward voltage of the output diode in the secondary side

If SDX/EN terminal is connected to VIN terminal, duty could be more than 50% and unexpected output voltage might occur when turning ON/OFF. Please refer to "8. Enable Voltage" on page 15 of the application information for the enable control with VIN terminal.

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(2) VIN Under Voltage Lock-Out (VIN UVLO)

When the input voltage (V_{IN}) falls below 6.2V (Typ), it will be detected, followed by SW terminal becomes Hi-Z then output turns OFF.

When the input voltage (V_{IN}) rises to above 6.9V (Typ), it automatically recovers thorough the soft start.

(Hysteresis voltage: 0.7V (Typ))

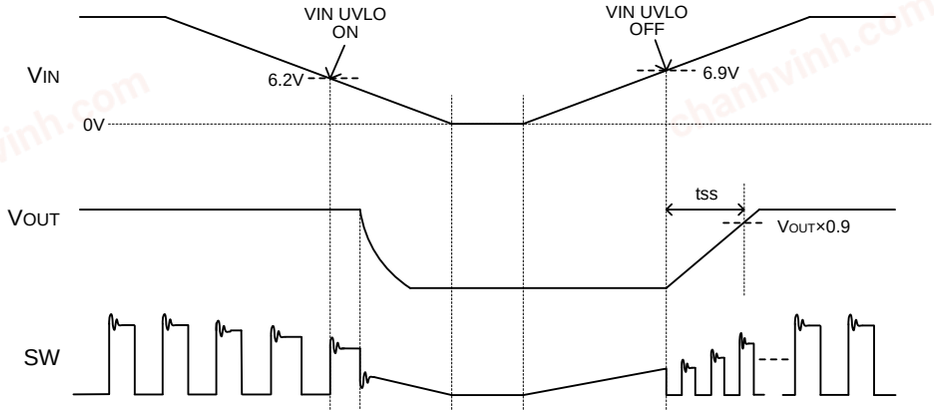


Figure 16. VIN UVLO Timing Chart

(3) Thermal Shutdown Protection (TSD)

When the internal chip (Junction) temperature exceeds Tj=175°C (Typ) ,it will be detected, followed by SW terminal becomes Hi-Z, then output turns OFF.

When Tj decreases below 150°C (Typ), it automatically recovers through the Soft Start.

Note that the thermal shutdown circuit is designed to shutdown the IC from thermal runaway under abnormal circumstances with the temperature exceeding Tjmax = 150°C. It is not designed to protect or guarantee the application set. Please refrain from using this function as a protection design of the application set.

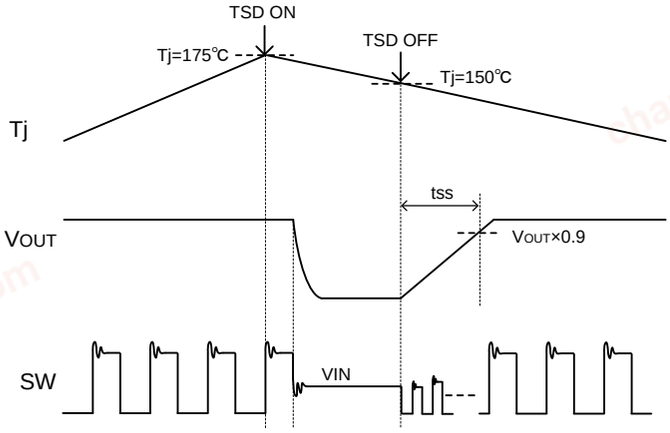


Figure 17. TSD Timing Chart

(4) Over Current Protection (OCP)

When the peak current reaches 2.75A (Typ) during the built-in N-channel MOSFET is ON, it will be detected, followed SW terminal becomes Hi-Z, then N-channel MOSFET turns OFF. It is detected per switching cycle, and output voltage decreases as ON duty is limited.

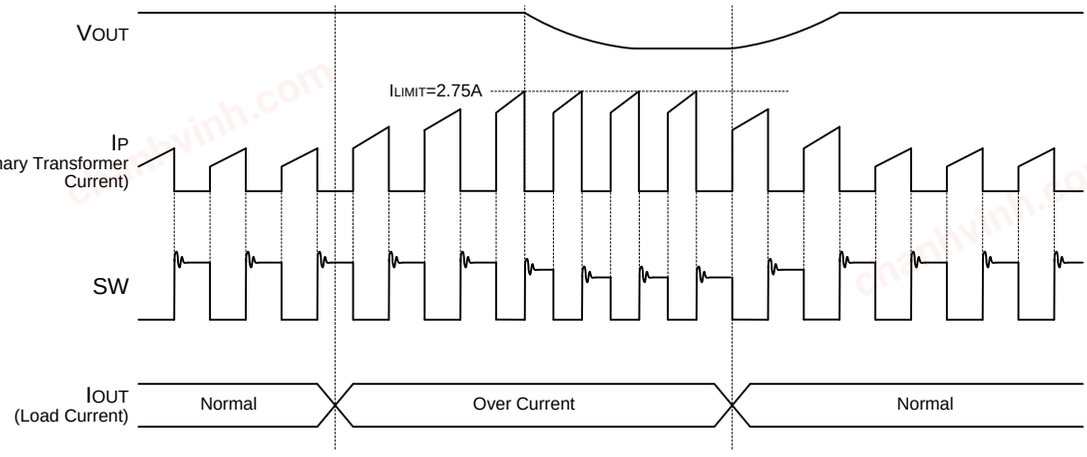


Figure 18. OCP Timing Chart

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3. Output Voltage

SW terminal voltage is higher than input voltage (VIN) when the built-in N-Channel MOSFET is OFF.
This primary flyback voltage (the gap between SW terminal voltage and VIN) contains the information of the secondary output voltage.
SW terminal voltage can be calculated as follows:

$$V_{SW} = V_{IN} + \frac{N_P}{N_S} \times \left(V_{OUT} + V_F + I_S \times ESR\right) \quad [\mathrm{V}]$$

where:
V_{SW} is the SW terminal voltage
I_S is the transformer current in the secondary side
ESR is the total impedance in the secondary side
(transformer wirewound resistance of the secondary side, PCB impedance, and etc.)

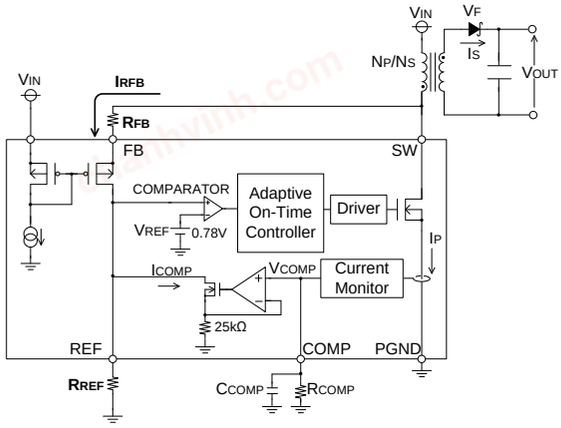


Figure 19. Control Block Diagram

This primary flyback voltage is converted to the current IRFB by RFB resistor. As FB terminal voltage almost equals to VIN voltage due to the differential circuit of VIN, IRFB can be expressed by following equation:

$$I_{RFB} = \frac{V_{SW} - V_{FB}}{R_{FB}} = \frac{\frac{N_P}{N_S} \times \left(V_{OUT} + V_F + I_S \times ESR\right)}{R_{FB}} \quad [\mathrm{A}]$$

where:
I_{RFB} is the FB input current
V_{FB} is the FB terminal voltage
R_{FB} is the external resistance between the FB-SW terminals

REF terminal voltage can be expressed as follows since IRFB flows into RREF resister.

$$V_{REF} = \frac{R_{REF}}{R_{FB}} \times \frac{N_P}{N_S} \times \left(V_{OUT} + V_F + I_S \times ESR\right) \quad [\mathrm{V}]$$

where:
V_{REF} is the REF terminal voltage
R_{REF} is the external resistance between the REF–AGND terminals
(The IC is designed on the assumption that this value is 3.9kΩ.)

The REF terminal voltage is input into the comparator and compared with the IC internal reference voltage (0.78V(Typ)). Since the loop gain of the whole system is high, the REF terminal voltage can be equal to the reference voltage in the IC. Therefore, the output voltage VOUT and the REF terminal voltage VREF are as follows:

$$V_{OUT} = \frac{R_{FB}}{R_{REF}} \times \frac{N_S}{N_P} \times V_{REF} - V_F - I_S \times ESR \quad [\mathrm{V}]$$

That is, the output voltage VOUT can be set by the primary and secondary side turns ratio of the transformer, and the ratio of the resistances RFB and RREF. VF and ESR cause an output voltage error.
The feedback resistor RFB can be expressed as follows from the relative quation with VOUT :

$$R_{FB} = \frac{R_{REF}}{V_{REF}} \times \frac{N_P}{N_S} \times \left(V_{OUT} + V_F + I_S \times ESR\right) \quad [\Omega]$$

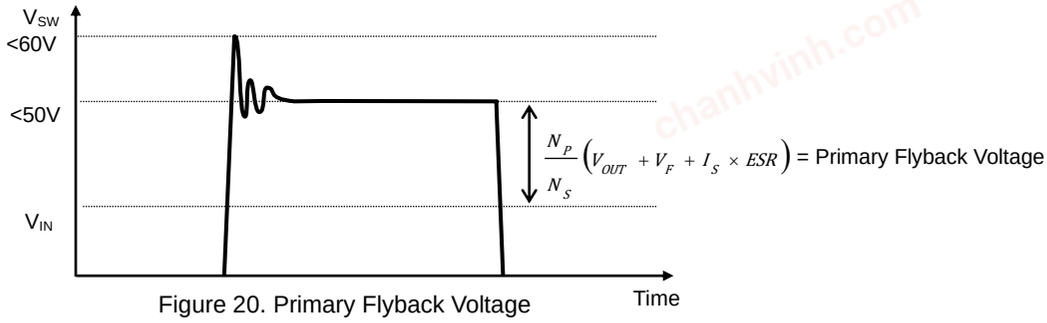


Figure 20. Primary Flyback Voltage

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4. Transformer

(1) Turns Ratio

Turns ration is the parameter which determines the output voltage, maximum output voltage, duty and SW terminal voltage.The duty of a flyback converter can be expressed by the following equation:

$$Duty = \frac{\frac{N_P}{N_S} \times (V_{OUT} + V_F)}{V_{IN} + \frac{N_P}{N_S} \times (V_{OUT} + V_F)}$$

Feedback voltage is monitored by the SW terminal and duty needs to be below 50% for the stable control. The minimum duty will be 20% due to the limitation of the min ON time and the turns ratio needs to fulfill below conditions:

$$\frac{1}{4} \times \frac{V_{IN}}{V_{OUT} + V_F} < \frac{N_P}{N_S} < \frac{V_{IN}}{V_{OUT} + V_F}$$

(2) Primary Side Inductance

Flyback converter has the secondary pole from the primary inductance and the secondary output capacitor. Therefore, for operational stability, selection of the primary side inductance value is important. In addition, as the primary inductance influences the maximum load, please follow below conditions:

$$\frac{1}{2} \times \frac{V_{IN}{}^2 \times T \times Duty^2 \times \eta}{I_{LIMIT_MIN} \times Duty \times V_{IN} \times \eta - V_{OUT_MAX} \times I_{OUT_MAX}} < L_P < \frac{2 \times Duty \times V_{IN}{}^2}{(V_{OUT} + V_F) \times I_{OUT_MAX} \times \pi \times f_{SW}} \quad [H]$$

where:

L_P is Primary side inductance
T is Switching output cycle
η is Efficiency
I_{LIMIT_MIN} is Minimum over current limit
I_{OUT_MAX} is Maximum Load current
f_{SW} is Switching frequency

(3) Leakage Inductance

Transformer leakage inductance causes SW terminal ringing when the built-in N-Channel MOSFET turns OFF.
A snubber circuit is recommended in order to avoid the peak voltage of the ringing from exceeding the absolute maximum rating (60V). Furthermore, after a voltage spike occurs, ringing is also caused. In order to prevent erroneous detection of the secondary output voltage, the ringing must be converged within 250ns (Typ).

When the built-in N-Channel MOSFET turns ON, reverse spike voltage in the output diode is generated. Note that this spike voltage must not exceed the diode rating voltage.

(4) Winding Resistance

Either primary or secondary winding resistance will reduce overall power efficiency. Moreover, secondary winding resistance lowers the output voltage. Therefore, a transformer with smaller winding resistance is recommended.

(5) Saturation Current

The current in the primary transformer will not be transferred to the secondary if the core is saturated due to the exceeded current. When the core is saturated, the inductance value decreases and the current drastically increases. The current in the transformer should not exceed its rated saturation current.

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5. Output Capacitor

Selecting the secondary side output capacitor value is important for a stable operation.
Please select the value which fulfils below condition.

$$C_{OUT} = 1.6 \times 10^{-9} \times \frac{1}{L_P} \times \left(\frac{N_P}{N_S} \times Duty \right)^2 \quad [\mathrm{F}]$$

where:
C_{OUT} is Output capacitor

In addition, as secondary side output voltage rises through soft start time (tSS), please consider below equation when choosing an output capacitor. Over current protection operates due to the inrush current especially when the capacitance value is extremely large, thus, start-up failure might occur.

$$C_{OUT} \leq \frac{1}{2} \times \frac{t_{SS} \times \left\{ \left(I_{LIMIT_MIN} \times \frac{N_P}{N_S} \right) \times (1 - Duty) - I_{OUT_MAX} \right\}}{V_{OUT}} \quad [\mathrm{F}]$$

where:
t_{SS} is Soft start time

6. Input Capacitor

Use ceramic capacitor for the input capacitor and place the input capacitor as close as possible to VIN terminal. Please refer to the “PCB Layout Design Guidelines” on page 19 for the design as malfunctions might occur due to the layout pattern or the position of the capacitor.
As for the capacitance value of the input capacitor, the ripple voltage of VIN terminal needs to be below 4% of the input voltage.
And, make sure that ripple voltage is suppressed when load changes or start up.

7. Output Diode

Since the forward voltage VF of the output diode becomes an error factor in the output voltage, a Schottky barrier diode of small VF is recommended. When selecting a diode, note that forward current must not exceed the rated values. And, when the built-in N-Channel MOSFET is ON, the output diode or reverse voltage VR decrease is expressed by the following equation:

$$V_R = V_{IN} \times \frac{N_S}{N_P} + V_{OUT} \quad [\mathrm{V}]$$

Furthermore, ringing occurs to the reverse voltage VR when built-in N-Channel MOSFET turns ON. Please prevent the peak voltage from exceeding the rated value of the output diode.

8. Enable Voltage

This IC is shut downed when SDX/EN voltage is below 0.9V (Typ).
If the voltage becomes above 2.0V (Typ) when SDX/EN terminal voltage is rising, IC goes to enable state and starts up. (Hysteresis voltage: 0.2V (Typ))

Enable control with VIN terminal is done by dividing the VIN terminal and GND terminal with R1 and R2 resistors connecting to SDX/EN terminal, as shown in Figure 25. The enable voltage when VIN is rising can be set with the following equation:

$$V_{VIN_ENABLE} = \frac{2.0V \times (R_1 + R_2)}{R_2} \quad [\mathrm{V}]$$

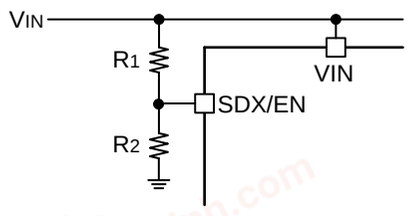


Figure .21 Enable Control with VIN terminal

Disable voltage when VIN is falling can be set with the following equation:

$$V_{VIN_DISABLE} = \frac{1.8V \times (R_1 + R_2)}{R_2} \quad [\mathrm{V}]$$

Since the control system of this IC needs to operate with 50% duty or less, set disable voltage which fulfils the following equation:

$$V_{VIN_DISABLE} > \frac{N_P}{N_S} \times (V_{OUT} + V_F) \quad [\mathrm{V}]$$

Please note that the clamping element inside the IC will turn ON and the inflow current occurs if the SDX/EN terminal voltage rises above 5V.

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9. Minimum Load Current

To achieve a stable output voltage, the built-in N-Channel MOSFET senses and feeds back information on the output voltage on the secondary side (which was isolated by the transformer) by using the SW terminal voltage on the primary side (during OFF time). Meaning, the output will not be regulated in any case unless the built-in N-Channel MOSFET is in the switching operation.

During light load, the switching operation uses minimum ON-Time. The output voltage may rise when there is a small load current since it will supply the least amount of energy to the secondary side output. Therefore, it is necessary to add a dummy resistor etc. to the output in order to secure minimum load current.

The required minimum load current (I_{OUT_MIN}) can be expressed by:

$$I_{OUT_MIN} = 7.5 \times 10^{-9} \times \left\{ \frac{V_{IN}{}^2}{L_P \times V_{OUT}} \right\} \quad [A]$$

10. Switching Frequency Changing Point

During light load, high efficiency is achieved by changing the switching frequency according to the load current.

The load current equation where the switching frequency begins to fall from the fixed 400kHz (Typ) is expressed following equation:

$$I_{OUT_fsw} = \frac{1}{2} \times \left\{ \frac{400kHz \times \left(V_{IN} \times t_{ON_MIN}\right)^2}{L_P \times V_{OUT}} \right\} \quad [A]$$

where

t_{ON_MIN} is the Minimum On time

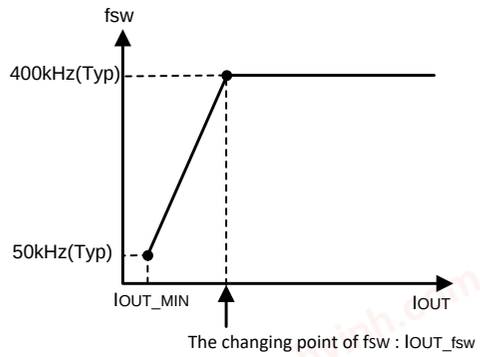


Figure 22. Switching Frequency vs Load Current Image

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11. Load Compensation

The relational expression of VOUT shows that VF and ESR are the factors leading to poor load regulation. For an application which these factors cause the problem, an ideal load regulation can be obtained using load compensation function. Load compensation mechanism is explained below. In the application wherein output voltage accuracy in particular is not required, load compensation function can be cancelled by short-circuiting the COMP terminal to GND.

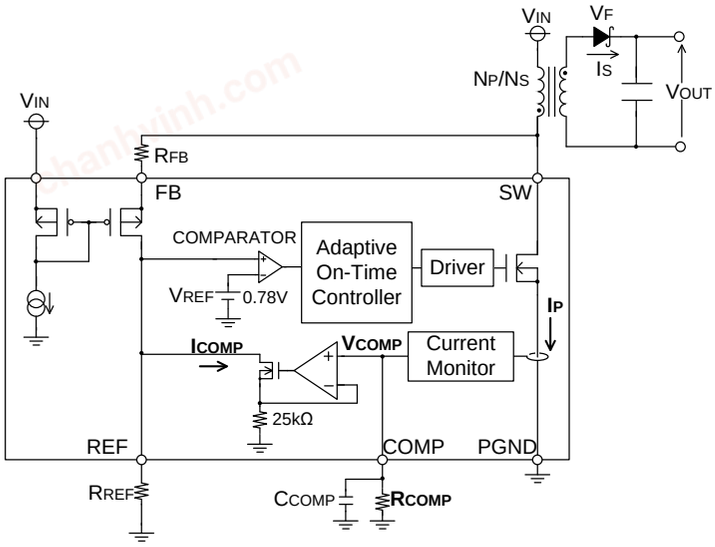


Figure 23. Load Compensation Functional Block Diagram

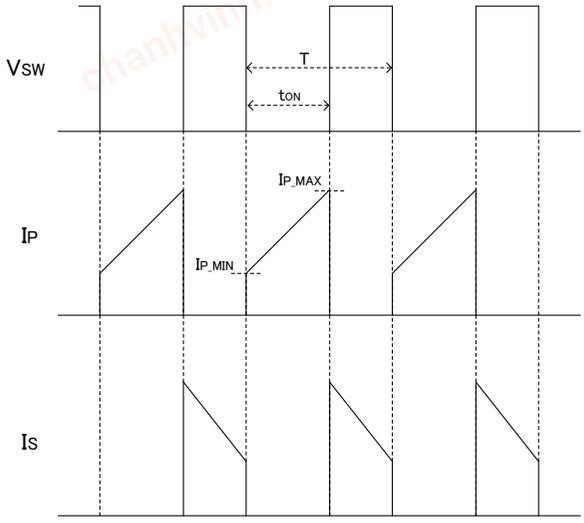


Figure 24. Monitor of the Amount of Load Compensation (Continuous Mode)

VOUT voltage drop is compensated corresponding to the average current of the primary transformer current IP.

Since IP and IS have a relationship as indicated in the following equation, the load compensation value is determined by assuming IS from IP and then adjusted by using external CR of the COMP terminal. The current of K・IP is injected to the COMP terminal from the Current Monitor block in the Figure. 23 and then converted to VCOMP through RCOMP resistor externally attached to COMP terminal.
K here is the compression magnification and indicated as 1/50k.
The upper limit of VCOMP operating voltage is limited in the internal circuit. Set RCOMP below 0.5V.

$$I_P = \frac{N_S}{N_P} \times I_S \quad [\mathrm{A}]$$

$$V_{COMP} = K \times I_P \times R_{COMP} \leq 0.5V$$

Steep changes in ICOMP may make the operation of the loop unstable.
Therefore, CCOMP is needed to stabilize VCOMP.
Recommended values of CCOMP are from 0.01μF to 0.1μF. By the addition of CCOMP, VCOMP becomes:

$$V_{COMP} = K \times R_{COMP} \times I_{P_AVE}$$

$$= K \times R_{COMP} \times \frac{I_{P_MIN} + I_{P_MAX}}{2} \times \frac{t_{ON}}{T} \quad [\mathrm{V}]$$

$$I_{COMP} = \frac{V_{COMP}}{25k\Omega} \quad [\mathrm{V}]$$

where:
I_{P_ave} = Average transformer primary side current
R_{COMP}= External resistance for ICOMP adjustment
t_{ON} = ON-Time of built-in N-Channel MOSFET

How to decide the amount of load compensation and ICOMP setup by adjustment of RCOMP is explained next.
The feedback current which originally flows into RREF is partially lost by ICOMP due to the load compensation function. As a result, in order to compensate this, the H level of VSW increases and recovers the dropped output voltage.

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While the load compensation function is not operating, VOUT, as described previously, will now be:

$$V_{OUT} = \frac{R_{FB}}{R_{REF}} \times \frac{N_S}{N_P} \times V_{REF} - V_F - I_{S_AVE} \times ESR \qquad [V]$$

where:

I_{S_AVE} is the average transformer secondary side current

When ICOMP occurs, the load compensation function operates and VOUT becomes the following equation. The voltage VOUT increases by ICOMP.

$$V_{OUT} = \frac{N_S}{N_P} \times \left(\frac{V_{REF}}{R_{REF}} + I_{COMP} \right) \times R_{FB} - V_F - I_{S_AVE} \times ESR \qquad [V]$$

$$\frac{K \times R_{COMP} \times I_{P_AVE}}{25k\Omega} \times \frac{N_S}{N_P} \times R_{FB} = I_{S_AVE} \times R_{VF} + I_{S_AVE} \times ESR$$

In order to remove VF and ESR by using ICOMP, the following equation is needed.

$$I_{COMP} \times \frac{N_S}{N_P} \times R_{FB} = V_F + I_{S_AVE} \times ESR$$

Next, linearity approximation of the change of VF to IS is carried out by RVF, and RCOMP which adjusts ICOMP from the expression mentioned earlier is calculated.

$$\frac{K \times R_{COMP} \times I_{P_AVE}}{25k\Omega} \times \frac{N_S}{N_P} \times R_{FB} = I_{S_AVE} \times R_{VF} + I_{S_AVE} \times ESR$$

$$\frac{K \times R_{COMP}}{25k\Omega} \times \left(\frac{N_S}{N_P} \right)^2 \times R_{FB} = R_{VF} + ESR$$

$$R_{COMP} = 25k\Omega \times \frac{R_{VF} + ESR}{K \times R_{FB}} \times \left(\frac{N_P}{N_S} \right)^2 \qquad [\Omega]$$

Although the setting of the theoretical value of RCOMP was shown, RVF, ESR, and RFB are dependent on the environment, such as used parts and the mounting board.
Therefore, when determining the actual value of RCOMP, monitor VOUT in the used load current range and adjust RCOMP accordingly.

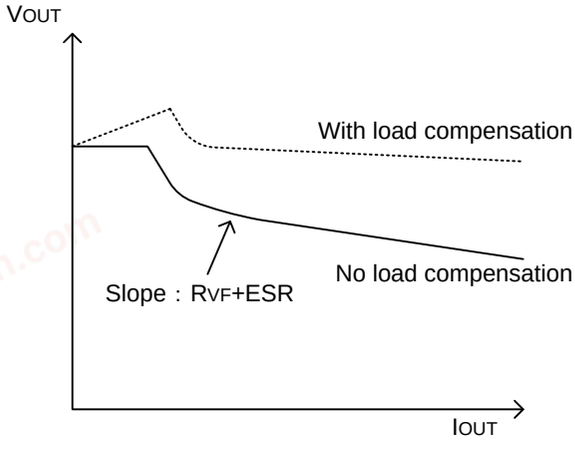
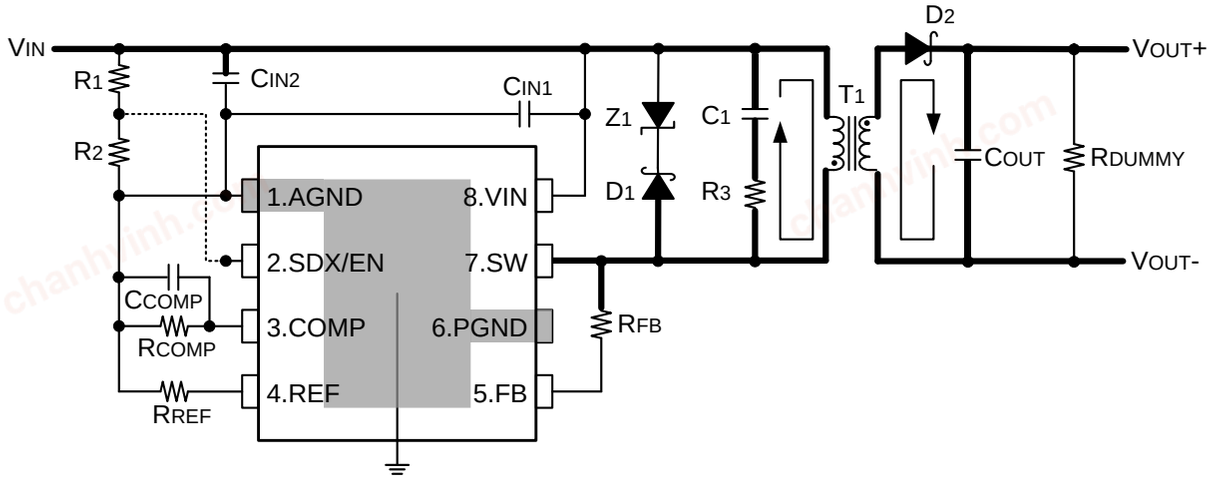


Figure 25. Load Compensation Image

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PCB Layout Design Guidelines



The dotted line is the image of the wiring in another layer.

Figure 26. Application Circuit Block Diagram

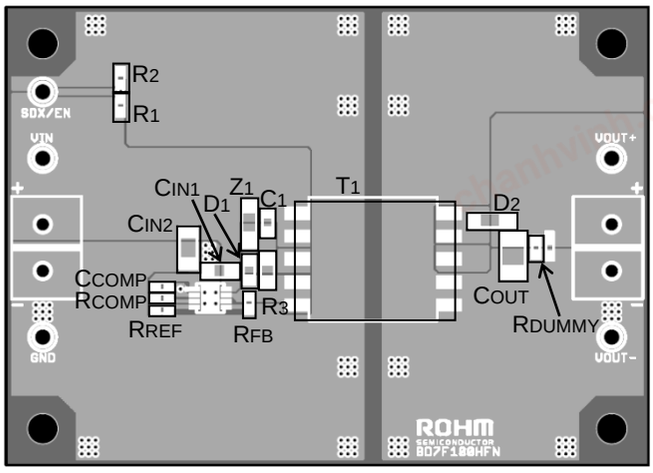
PCB layout greatly affects the stable operation of the IC. Depending on the layout, the specs of the IC might not be secured or IC might not operate correctly.
Please take the following points into consideration when designing the PCB layout.

1. Place input ceramic capacitors C_{IN1} and C_{IN2} as close as possible to VIN terminal on the same PCB surface with IC.
2. Shorten the thick line as short as possible with wide width pattern.
3. Place R_{REF} as close as possible to REF terminal.
4. Place R_{FB} as close as possible to FB terminal.
5. Place transformer T_1 close to SW terminal and make the current loop indicated as an arrow (primary side) short. In addition, make the pattern of the SW node as thick and short as possible.
6. Place output diode D_2 close to SW terminal and make the current loop indicated as an arrow (secondary side) short.
7. In case of multilayer board, do not place GND layer or V_{OUT-} node pattern in the internal layer that is just below the SW node pattern and D_2 anode pattern.
8. R_{COMP} and C_{COMP} are for load compensation function. Short the COMP terminal to the GND when the load compensation function is not used.
9. Connect the exposed die pad to the GND plane.
10. Please note that temperature of the IC increase as BD7F200 has higher output power than BD7F100.

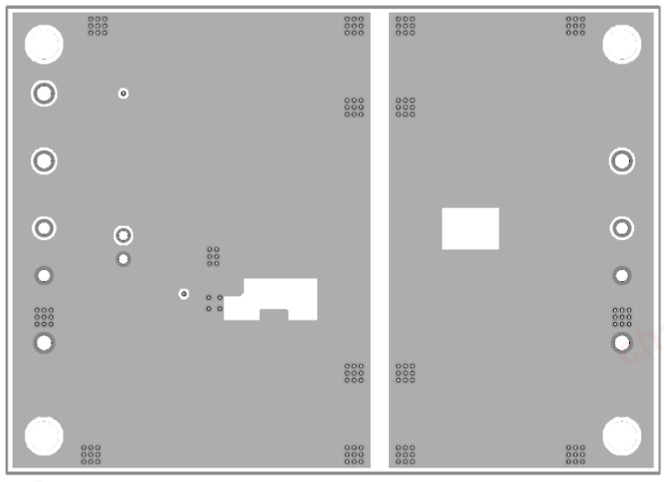
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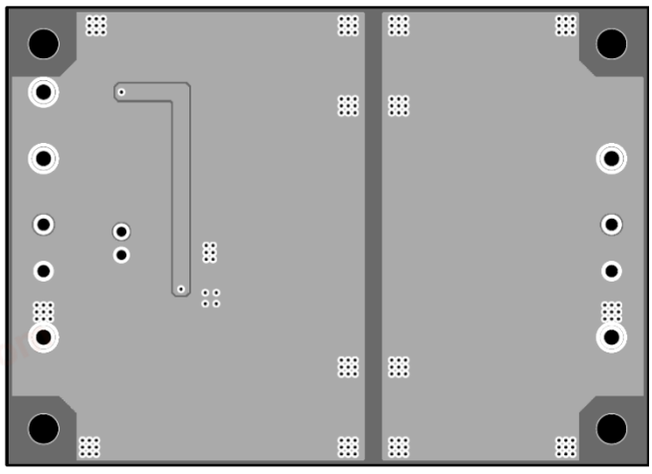
Reference Layout Pattern



Top Layer



Middle Layer

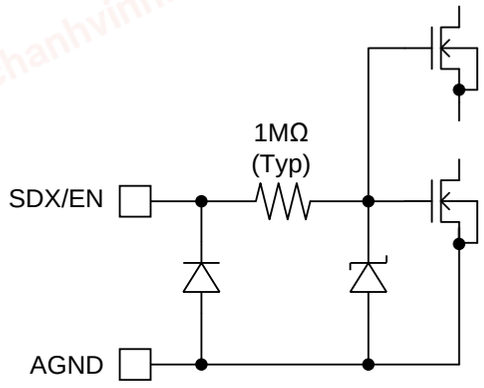
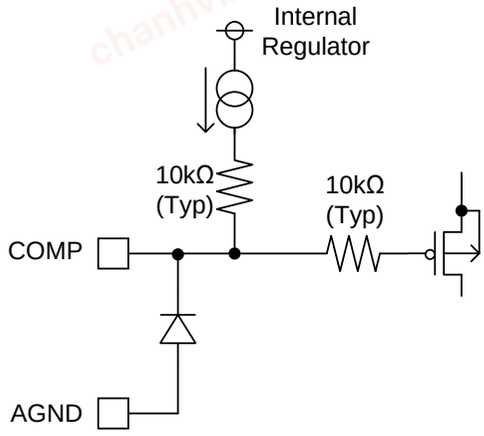
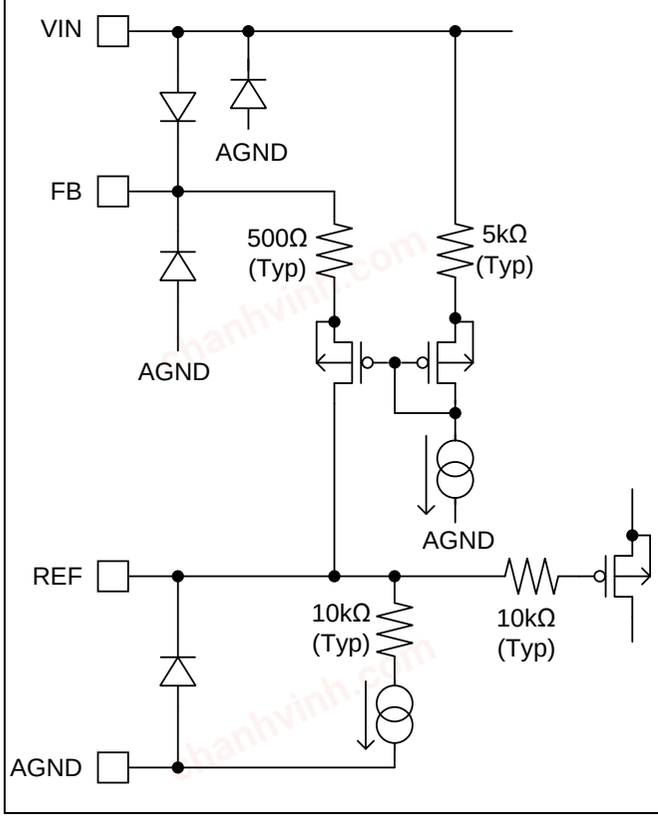
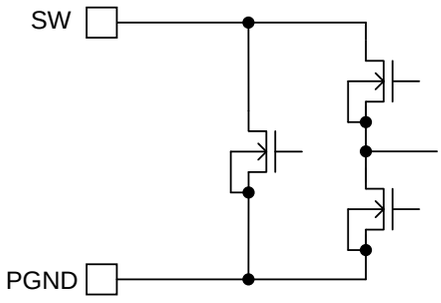


Bottom Layer

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I/O equivalent circuits

2. SDX/EN	3. COMP
	
4. REF, 5. FB	7. SW
	

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Operational Notes

1. **Reverse Connection of Power Supply**
   Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. **Power Supply Lines**
   Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. **Ground Voltage**
   Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. **Ground Wiring Pattern**
   When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. **Thermal Consideration**
   Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. **Recommended Operating Conditions**
   These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. **Inrush Current**
   When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. **Operation Under Strong Electromagnetic Field**
   Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

9. **Testing on Application Boards**
   When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

10. **Inter-pin Short and Mounting Errors**
    Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

11. **Unused Input Pins**
    Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

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Operational Notes – continued

12. **Regarding the Input Pin of the IC**
This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):
When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.
When GND > Pin B, the P-N junction operates as a parasitic transistor.
Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

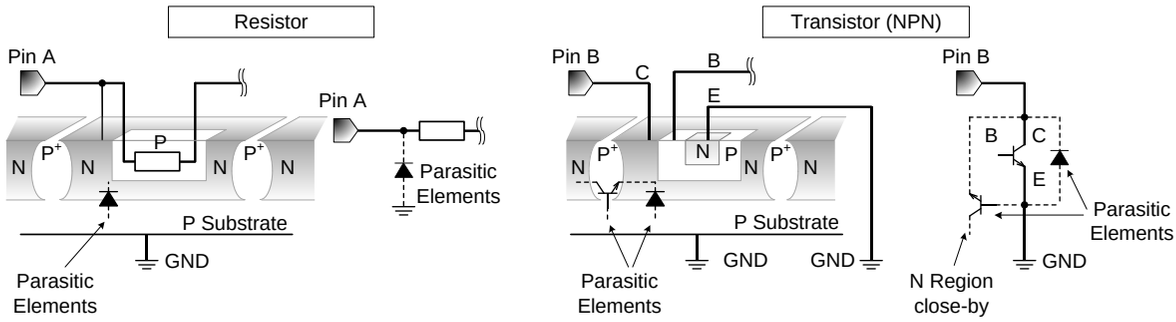


Figure 27. Example of monolithic IC structure

13. **Ceramic Capacitor**
When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

14. **Area of Safe Operation (ASO)**
Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

15. **Thermal Shutdown Circuit (TSD)**
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

16. **Over Current Protection Circuit (OCP)**
This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

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Ordering Information

B D 7 F 2 0 0 x H F N - L B T R

Part Number

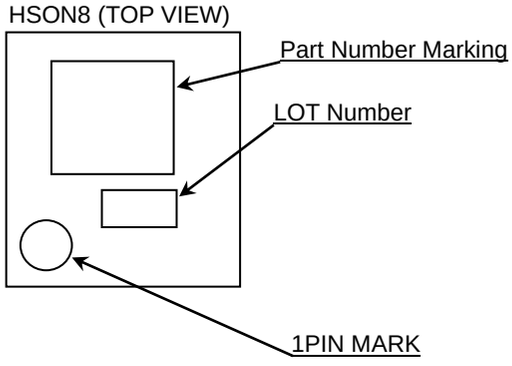
Production Line
NONE:Production Line A
U:Production Line B

Package
HFN:HSON8
EFJ:HTSOP-J8

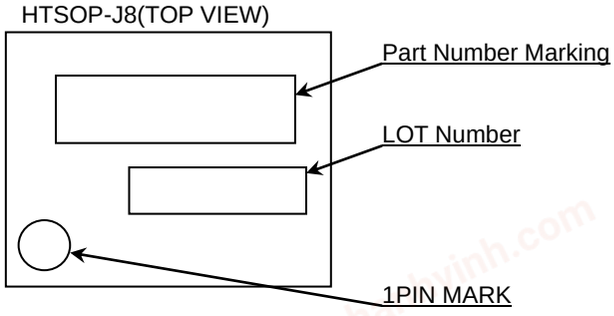
Product class
LB: For industrial applications
Packing, forming specification
TR: Embossed tape and reel
2500pcs (HSON8)
HR: Embossed tape and reel
250pcs (HSON8)
E2: Embossed tape and reel
3000pcs (HTSOP-J8)
H2: Embossed tape and reel
250pcs (HTSOP-J8)

Marking Diagrams

HSON8 (TOP VIEW)



HTSOP-J8(TOP VIEW)



Part Number Marking	Orderable Part Number
D7F200	BD7F200HFN-LBTR BD7F200HFN-LBHR

Part Number Marking	Orderable Part Number
D7F200	BD7F200EFJ-LBE2 BD7F200EFJ-LBH2
U7F200	BD7F200UEFJ-LBE2 BD7F200UEFJ-LBH2

Line up

Package	Orderable Part Number	Remarks
HSON8	BD7F200HFN-LBTR	-
	BD7F200HFN-LBHR	-
HTSOP-J8	BD7F200EFJ-LBE2	Production Line A *(Note 1)*
	BD7F200UEFJ-LBE2	Production Line B *(Note 1)*
	BD7F200EFJ-LBH2	Production Line A *(Note 1)*
	BD7F200UEFJ-LBH2	Production Line B *(Note 1)*

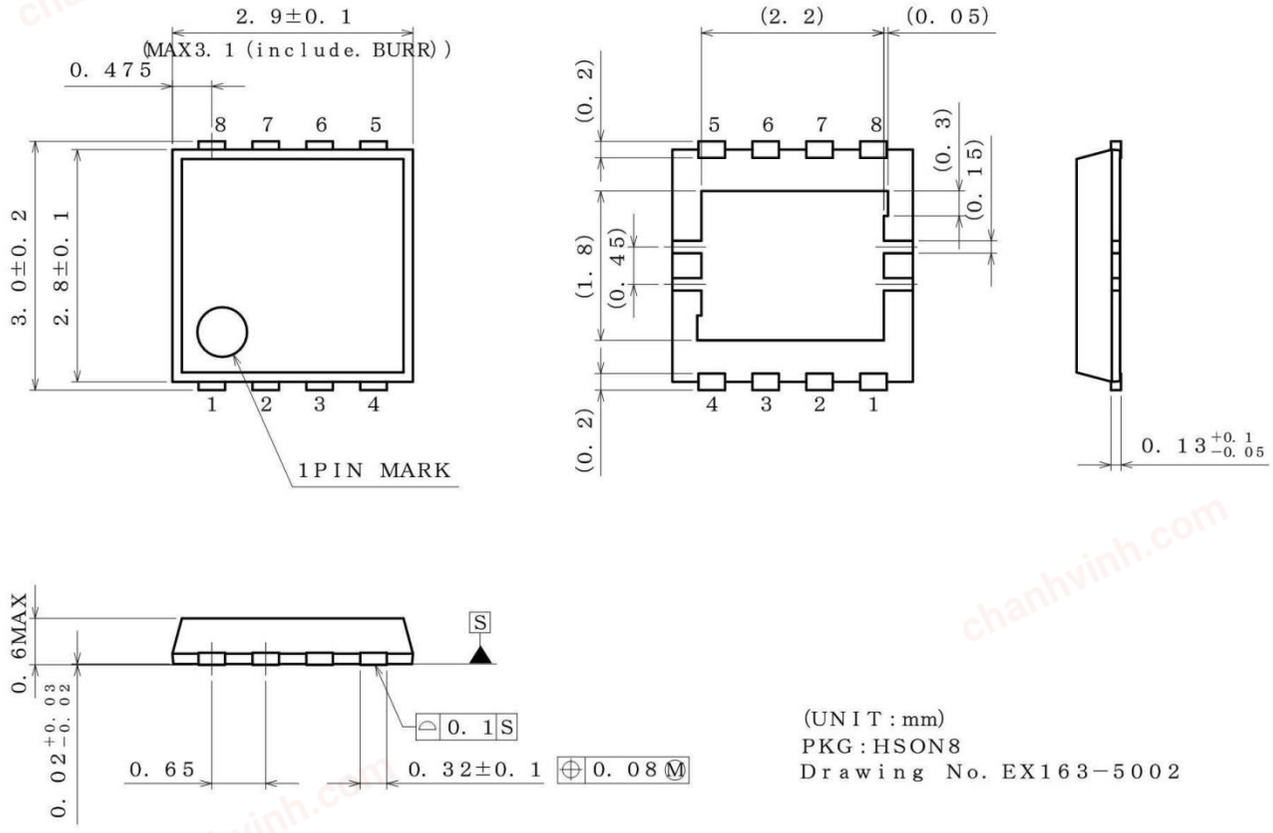
(Note 1) For the purpose of improving production efficiency, Production Line A and B have a multi-line configuration.
Electric characteristics noted in Datasheet does not differ between Production Line A and B.
Production Line B is recommended for new product.

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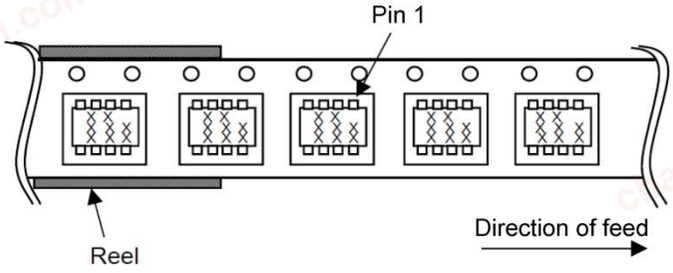
Physical Dimension, Tape and Reel Information

Package Name	HSON8



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	TR : 3000pcs / HR : 250pcs
Direction of feed	The direction is the pin 1 of product is at the upper right when you hold reel on the left hand and you pull out the tape on the right hand



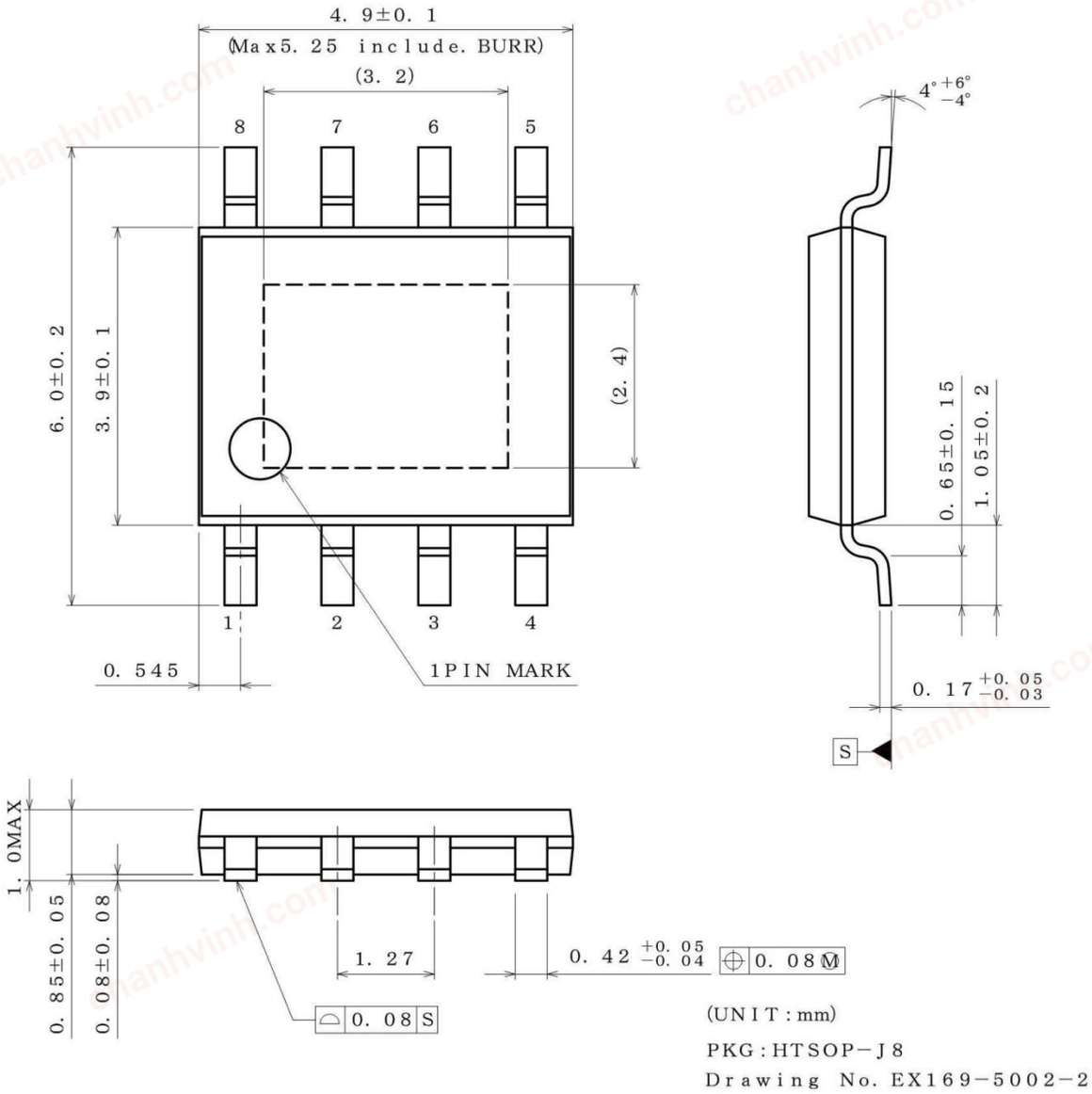
*Order quantity needs to be multiple of the minimum quantity.

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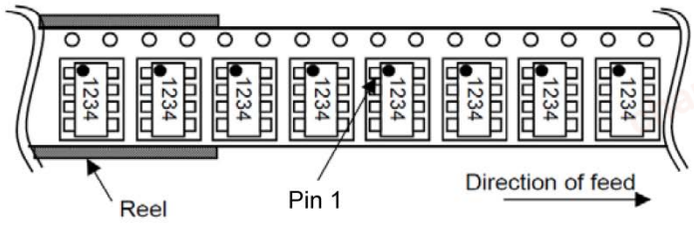
Physical Dimension, Tape and Reel Information

Package Name	HTSOP-J8



< Tape and Reel Information >

Tape	Embossed carrier tape
Quantity	E2 : 2500pcs / H2 : 250pcs
Direction of feed	The direction is the pin 1 of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand



*Order quantity needs to be multiple of the minimum quantity.

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Revision History

Date	Revision	Changes
10.Mar.2016	001	New production
24.Mar.2016	002	Add BD7F200EFJ-LB(HTSOP-J8 Package)
17.April.2017	003	P.4 Modified FB terminal absolute voltage P.24 Add small lots format P.25 P.26 Add small lots format
09.Dec.2022	004	Add BD7F200UEFJ-LB

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Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
   [a] Installation of protection circuits or other protective devices to improve system safety
   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   - [a] the Products are exposed to sea winds or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   - [b] the temperature or humidity exceeds those recommended by ROHM
   - [c] the Products are exposed to direct sunshine or condensation
   - [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

Precaution Regarding Intellectual Property Rights

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2. ROHM shall not have any obligations where the claims, actions or demands arising from the combination of the Products with other articles such as components, circuits, systems or external equipment (including software).

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General Precaution

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